Electronic properties of three- and low-dimensional semiconducting materials with Pb halide and Sn halide units

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Erratum

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I B Koutselas, L Ducasse and G C Papavassiliou 1996 *J. Phys.: Condens. Matter* **8** 1217–1227

On page 1223, first paragraph, the values for the theoretically estimated binding energy, Bohr radius and E_b(2D) should be 285 meV, 11.5 Å and 9.82 E_b(3D), rather than 191 meV, 14.2 Å and 6.58 E_b(3D), respectively.

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